

PMN30XPE 20 V, P-channel Trench MOSFET 16 April 2018

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Very fast switching •
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- Enhanced power dissipation capability of 1390 mW •

3. Applications

- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-7	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -5.3 A; T _j = 25 °C		-	28	34	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2. P	inning inf	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G () T
4	S	source	TSOP6 (SOT457)	
5	D	drain		
6	D	drain		S S
				017aaa259

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMN30XPE	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN30XPE	3F

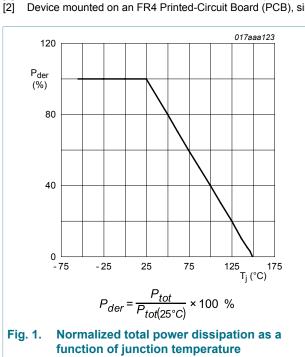
8. Limiting values

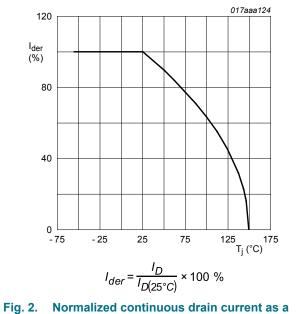
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-7	А
		V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-5.3	А
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-3.4	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-21	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	560	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode			·	·	
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.4	А

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².
 Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

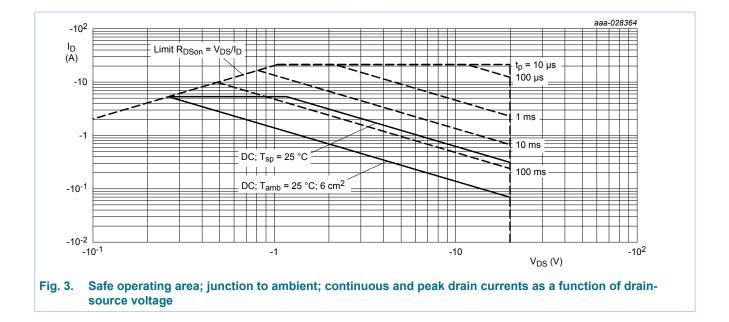




function of junction temperature

PMN30XPE

20 V, P-channel Trench MOSFET



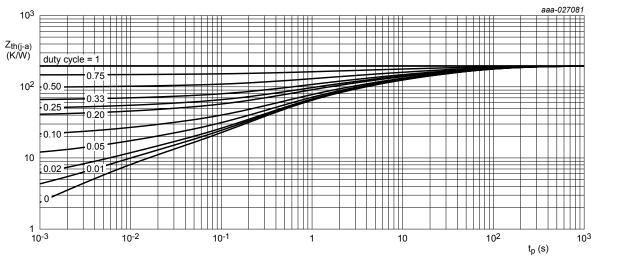
9. Thermal characteristics

	-	• ···			_		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		[1]	-	195	225	K/W
			[2]	-	78	90	K/W
		in free air, t ≤ 5 s	[2]	-	45	52	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	15	20	K/W

Table 6. Thermal characteristics

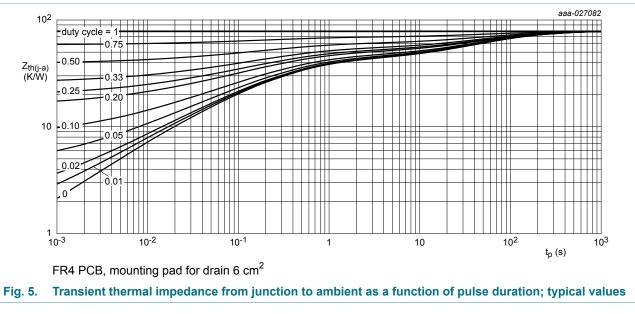
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



FR4 PCB, standard footprint



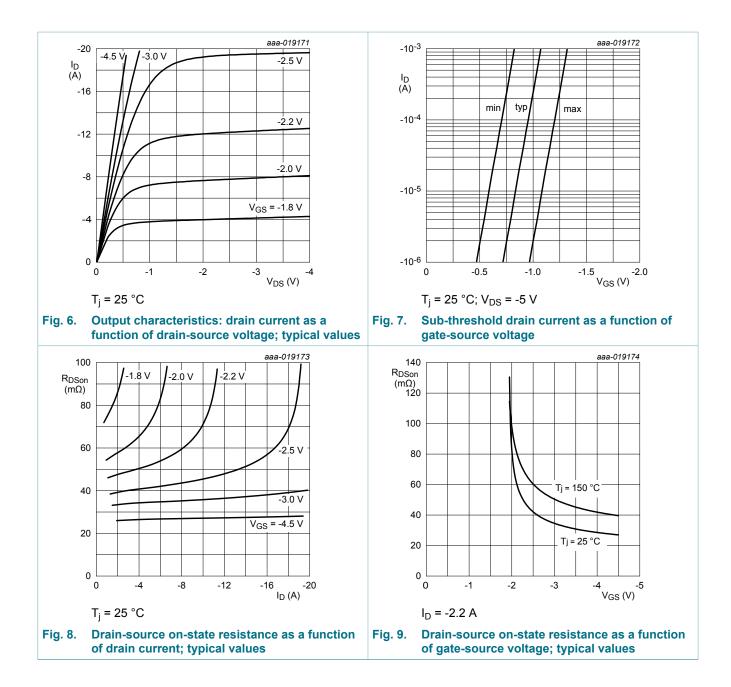


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.75	-1	-1.25	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	5	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-5	μA
		V_{GS} = 2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
		V_{GS} = -2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
R _{DSon} drain-source on-stat	drain-source on-state	V _{GS} = -4.5 V; I _D = -5.3 A; T _j = 25 °C	-	28	34	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -5.3 A; T _j = 150 °C	-	40	49	mΩ
		V _{GS} = -2.5 V; I _D = -4.1 A; T _j = 25 °C	-	42	57	mΩ
9 _{fs}	forward transconductance	V_{DS} = -10 V; I_D = -2 A; T_j = 25 °C	-	13	-	S
R _G	gate resistance	f = 1 MHz	-	10.4	-	Ω
Dynamic ch	aracteristics		I			
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -3 A; V _{GS} = -4.5 V;	-	11	17	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2	-	nC
Q _{GD}	gate-drain charge		-	2.5	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	1465	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	193	-	pF
C _{rss}	reverse transfer capacitance		-	133	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -3 A; V _{GS} = -4.5 V;	-	8	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	27	-	ns
t _{d(off)}	turn-off delay time	1	-	62	-	ns
t _f	fall time	1	-	28	-	ns
Source-drai	in diode	,			1	
V _{SD}	source-drain voltage	I _S = -1.4 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

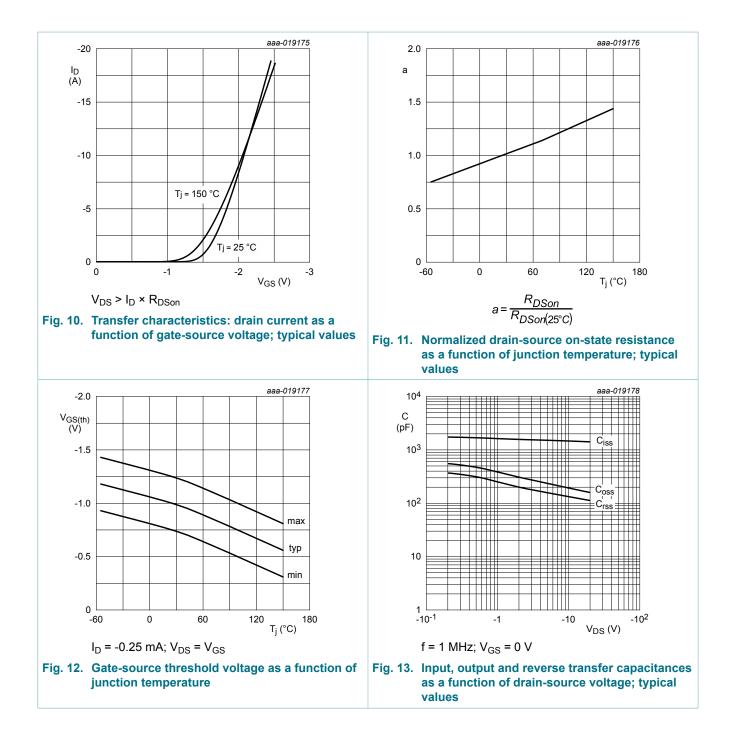
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20 V, P-channel Trench MOSFET



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20 V, P-channel Trench MOSFET

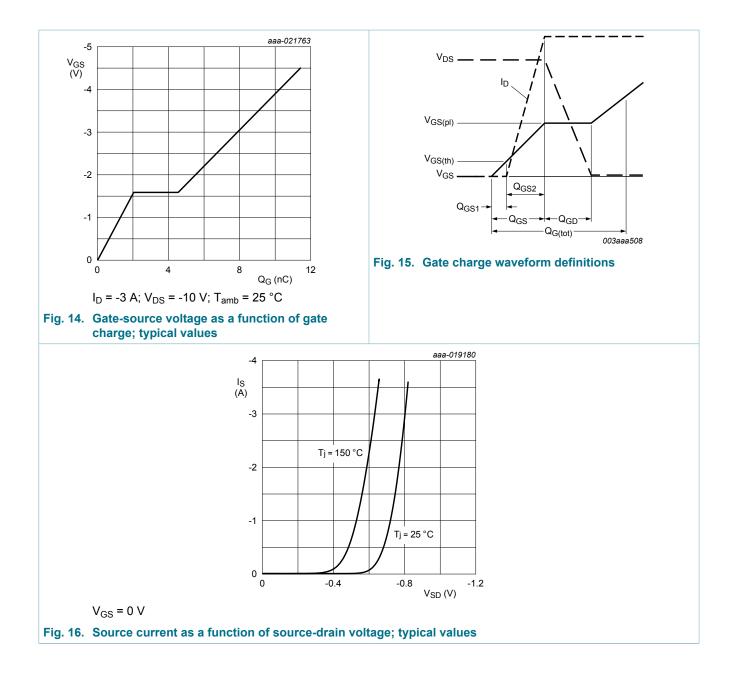


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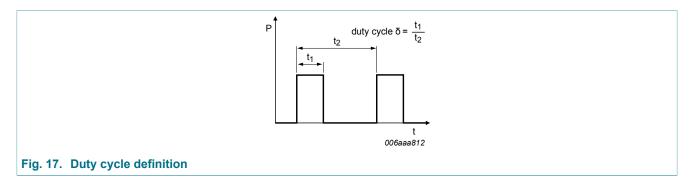
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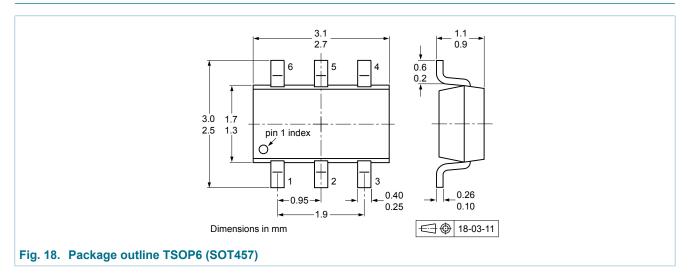
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11. Test information

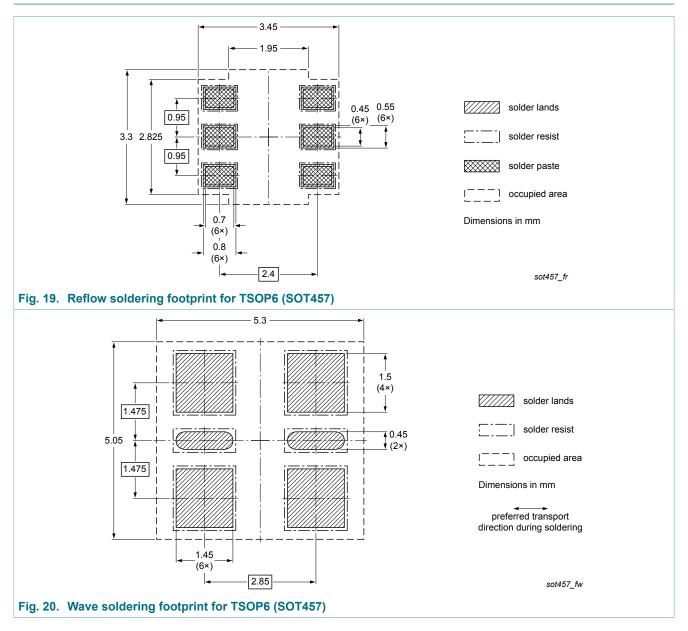


12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMN30XPE v.1	20180416	Product data sheet	-	-			

20 V, P-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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20 V, P-channel Trench MOSFET

16. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	5
10.	Characteristics	6
11.	Test information	10
12.	Package outline	10
13.	Soldering	11
14.	Revision history	12
15.	Legal information	13

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